NSN 5962-01-257-9638

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-257-9638

Body Length:
1.260 inches
Body Width:
0.300 inches
Body Height:
0.210 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and hermetically sealed and burn in and w/enable
nclosure Material:
Ceramic
nclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
19 input
Ferminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
2.0 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low leve
butput
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Yes - demil/mli

NSN 5962-01-257-9638

Memory Microcircuit - Page 2 of 2

Fiig: A458a0

